

产品概览

NSS40600CF8: 双极晶体管，低饱和压，PNP，6.0 A，40 V

欲看完整文档，请参阅数据表。

低饱和压双极晶体管是具有超低饱和压和高电流增益能力的微型表面贴装器件。这些器件设计用于需要经济、高效的能量控制的低电压、高速开关应用。

特性

- High Current, Low VCEsat, ESD Robust, High Current Gain, High Cut Off Frequency, Low Profile Package, Linear Gain (Beta)
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AECQ101 Qualified and PPAP Capable

优势

- Improved Circuit Efficiency, Decreased Battery Charge Time, Reduce component count, High Frequency Switching, Smaller Portable Product, No distortion

应用

- Load Switching, Battery Charging, External Pass Transistor, DC/DC Converter, Complimentary Driver, Current Extension & Low Drop Out Regulation, Cathode Florescent Lamp drive, Peripheral Driver - LEDs, Motors, Relays

终端产品

- Portable products

器件电气规格

产品	Pricing (\$/Unit)	Compliance	Status	Polarity	Type	V _{CE(sat)} Max (V)	I _C Cont. (A)	V _{CEO} Min (V)	V _{CB0} (V)	V _{EB0} (V)	V _{BE(sat)} (V)	V _{BE(on)} (V)	h _{FE} Min	h _{FE} Max	f _T Min (MHz)	P _{TM} Max (W)	Package Type
NSS40600CF8T1G	0.2133	Pb-free Halide free non AEC-Q and PPAP	Active	PNP	Low V _{CE(sat)}	0.075	6	40	40	7	0.9	0.9	250	-	100	2.75	Chip FET-8
SNSS40600CF8T1G	0.2347	AEC Qualified PPAP Capable Pb-free Halide free	Active	PNP	Low V _{CE(sat)}	0.075	6	40	40	7	0.9	0.9	250	-	100	2.75	Chip FET-8

欲了解更多信息，请联系您当地的销售支援 www.onsemi.cn。

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